



#### 100V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>C</sub> = +25°C
100V	16mΩ @ V <sub>GS</sub> = 10V	44A
1007	18mΩ @ V <sub>GS</sub> = 6.0V	41A

### **Description**

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize R<sub>DS(ON)</sub>, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and loadswitch.

### **Applications**

- Motor Control
- DC-DC Converters
- Power Management







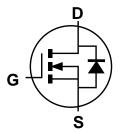
**Bottom View** 

#### **Features**

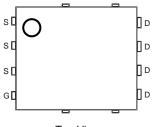
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications (PowerDI®)
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Internal Schematic



Top View Pin Configuration

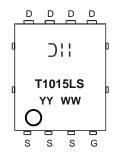
## Ordering Information (Note 4)

Part Number	Case	Packaging
DMT10H015LPS-13	PowerDI5060-8	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



)!! = Manufacturer's Marking T1015LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	$V_{DSS}$	100	V		
Gate-Source Voltage			$V_{GSS}$	±20	V
Continuous Drain Current (Note E) V 40V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	7.3 5.8	А
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	Steady $T_C = +25^{\circ}C$ State $T_C = +100^{\circ}C$		ΙD	44 28	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	150	Α		
Maximum Continuous Body Diode Forward Current (Note	Is	1.5	Α		
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cy	I <sub>SM</sub>	150	Α		
Avalanche Current (Note 7) L = 3mH			I <sub>AS</sub>	7.5	Α
Avalanche Energy (Note 7) L = 3mH			E <sub>AS</sub>	85	mJ

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	$P_{D}$	1.3	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	98	°C/W	
Total Power Dissipation	$T_C = +25^{\circ}C$	$P_{D}$	46	W
Thermal Resistance, Junction to Case	R <sub>0JC</sub>	2.7	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

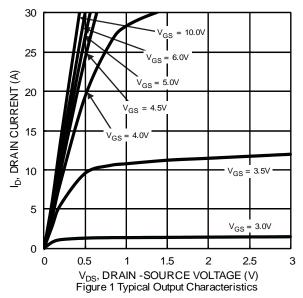
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	1	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.4	2.3	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		_	11	16		$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	13.5	18	mΩ	$V_{GS} = 6V, I_D = 20A$	
	, ,	_	18	25		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 5A	
Diode Forward Voltage	$V_{SD}$	_	0.9	1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	C <sub>iss</sub>		1871	_		$V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	1	261	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	-	6.9	_		1 = 11/1112	
Gate Resistance	R <sub>G</sub>	_	0.75	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	$Q_{G}$	_	33.3	_		V 50V L 40A	
Gate-Source Charge	Q <sub>GS</sub>	_	6.9	_	nC	$V_{DD} = 50V, I_D = 10A,$ $V_{GS} = 10V$	
Gate-Drain Charge	$Q_{GD}$	_	5.1	_		VGS = 10V	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.5	_			
Turn-On Rise Time	t <sub>R</sub>	_	7.0	_		$V_{DD} = 50V, V_{GS} = 10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	19.7	_	ns	$I_D = 10A$ , $R_G = 6\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	_	8.1	_			
Reverse Recovery Time	t <sub>RR</sub>	_	37.9	_	ns	1 100 di/dt 1000/up	
Reverse Recovery Charge	Q <sub>RR</sub>	_	51.9	_	nC	$I_F = 10A$ , di/dt = 100A/ $\mu$ s	

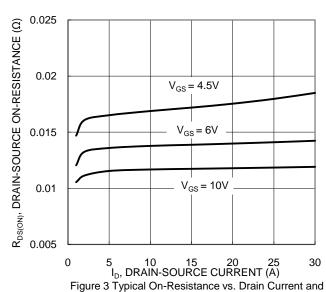
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

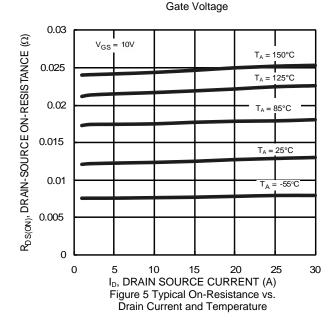
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

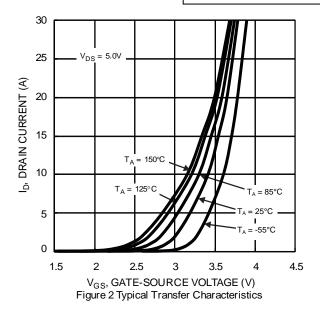


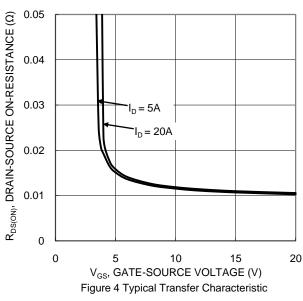


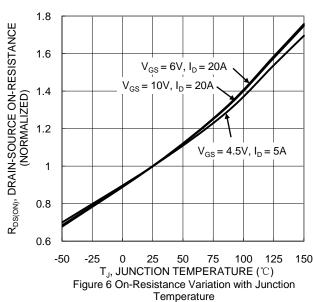






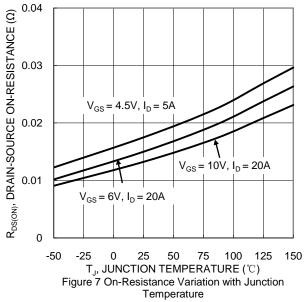


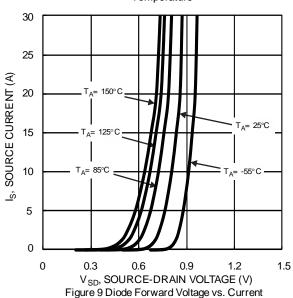


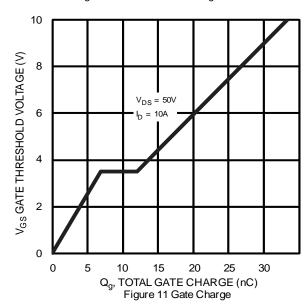












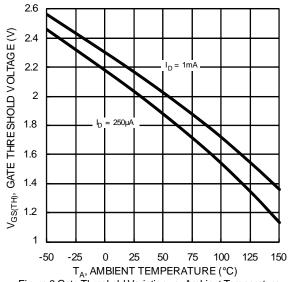
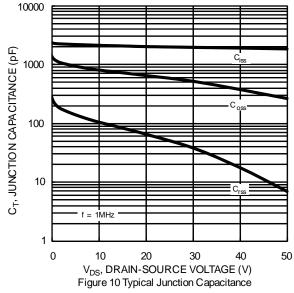
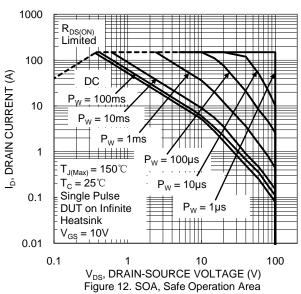
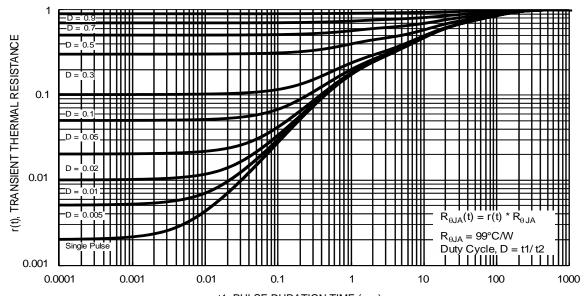


Figure 8 Gate Threshold Variation vs. Ambient Temperature









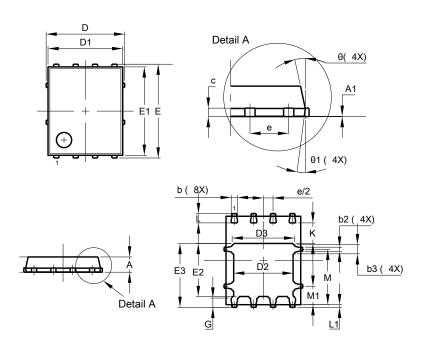
t1, PULSE DURATION TIME (sec) Figure 13 Transient Thermal Resistance



### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

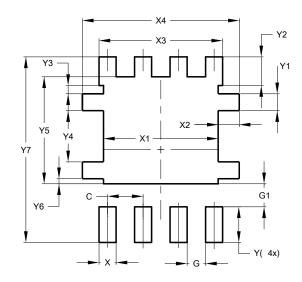


PowerDI5060-8						
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
Е	6.15 BSC					
E1	5.60	5.60 6.00 5				
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	,	1.27 BSC				
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
All Dimensions in mm						

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
<b>Y3</b> 0.295				
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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